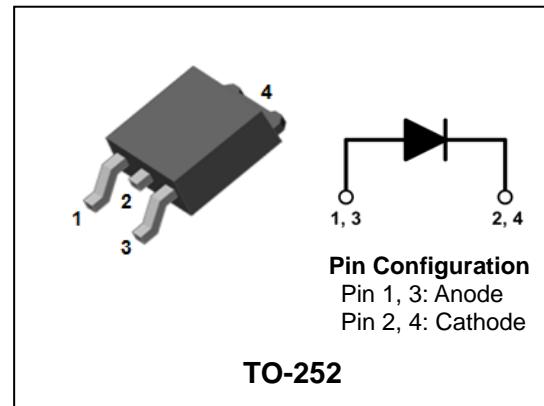


## LOW FORWARD DROP VOLTAGE SCHOTTKY RECTIFIER

### Features

- Low forward voltage drop
- Low power loss and High efficiency
- Low leakage current
- High surge capability
- “Green” device and RoHS compliant device



### Applications

- High efficiency SMPS
- Output rectification
- High frequency switching
- Freewheeling
- DC-DC converter systems

### Product Characteristics

$I_{F(AV)}$	10A
$V_{RRM}$	60V
$V_{FM}$ at 125 °C	0.55V
$I_{FSM}$	120A

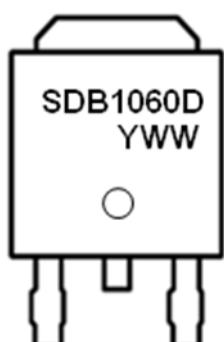
### Description

The SDB1060D is ideally suited for a full wave output rectifier in low switching power supplies, inverters and as free wheeling diodes.

### Ordering Information

Device	Marking Code	Package	Packaging
SDB1060D	SDB1060D	TO-252	Tape & Reel

### Marking Information



**SDB1060D = Specific Device Code**

**YWW = Year & Week Code Marking**

- . Y = Year Code

- . WW = Week Code

**Absolute Maximum Ratings (Limiting Values)**

Characteristic	Symbol	Value	Unit
Maximum repetitive reverse voltage Maximum working peak reverse voltage Maximum DC blocking voltage	$V_{RRM}$ $V_{RWM}$ $V_R$	60	V
Maximum average forward rectified current	$I_{F(AV)}$	10	A
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load per diode	$I_{FSM}$	120	A
Storage temperature range	$T_{stg}$	-45°C to +150°C	°C
Maximum operating junction temperature	$T_J$	150	°C

**Thermal Characteristics**

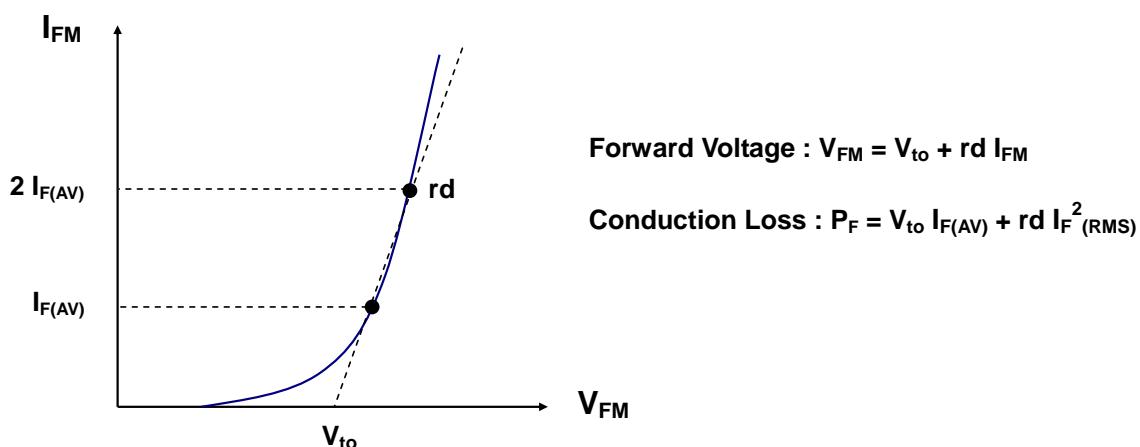
Characteristic	Symbol	Value	Unit
Maximum thermal resistance junction to case	$R_{th(j-c)}$	4.0	°C/W

**Electrical Characteristics**

Characteristic	Symbol	Test Condition	Min.	Typ.	Max.	Unit	
Peak forward voltage drop	$V_{FM}^{(1)}$	$I_{FM} = 10A$	$T_J=25^\circ C$	-	0.55	0.65	V
			$T_J=125^\circ C$	-	0.50	0.55	V
Reverse leakage current	$I_{RM}^{(1)}$	$V_R = V_{RRM}$	$T_J=25^\circ C$	-	-	1.5	mA
			$T_J=125^\circ C$	-	-	200	mA
Junction capacitance	$C_J$	$V_R = 4V_{DC}$ , $f=1MHz$	-	400	-	pF	

Note : (1) Pulse test :  $t_p \leq 380 \mu s$ , Duty cycle  $\leq 2\%$

To evaluate the conduction losses use the following equation:  $P_F = 0.35 I_{F(AV)} + 0.019 I_F^2 (RMS)$



## Rating and Characteristic Curves

Fig. 1) Typical Forward Characteristics

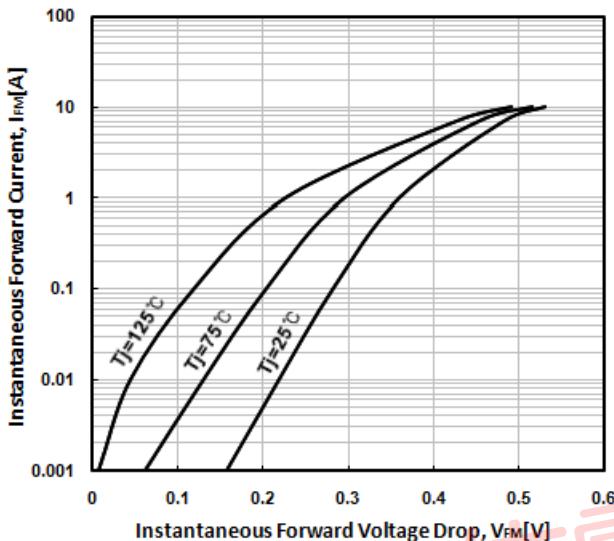


Fig. 2) Typical Reverse Characteristics

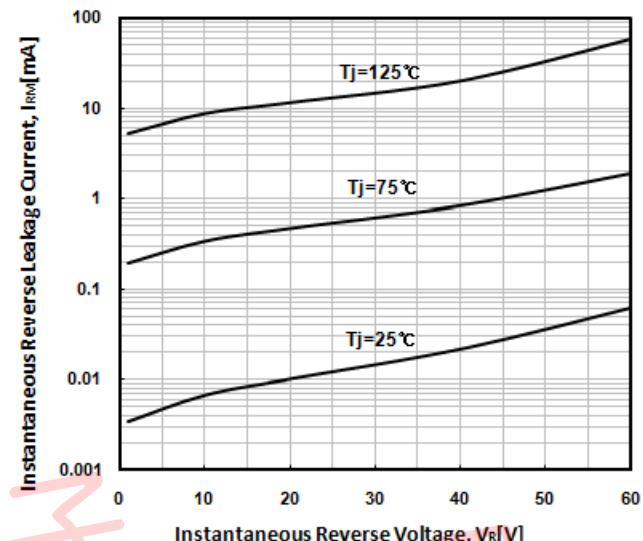


Fig. 3) Maximum Forward Derivative Curve

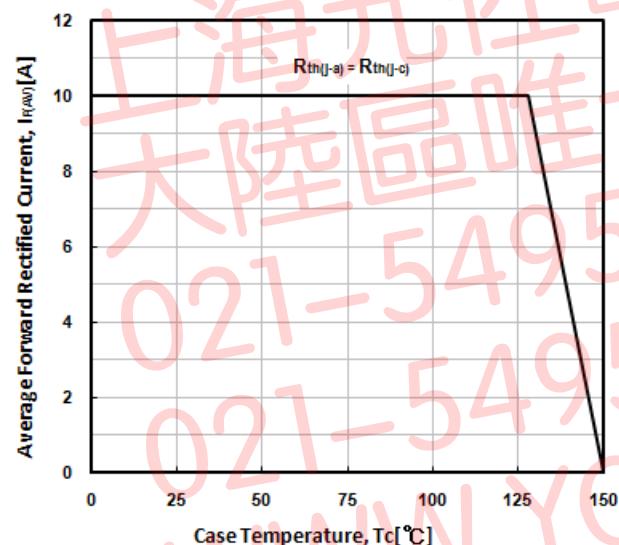


Fig. 4) Forward Power Dissipation

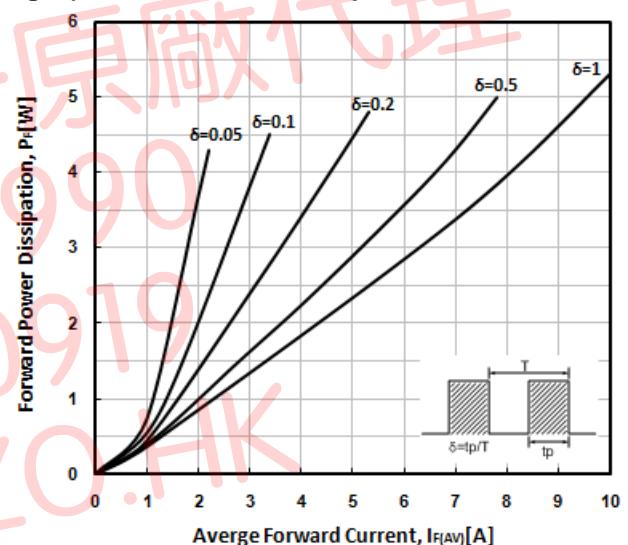


Fig. 5) Maximum Non-Repetitive Peak Forward Surge Current

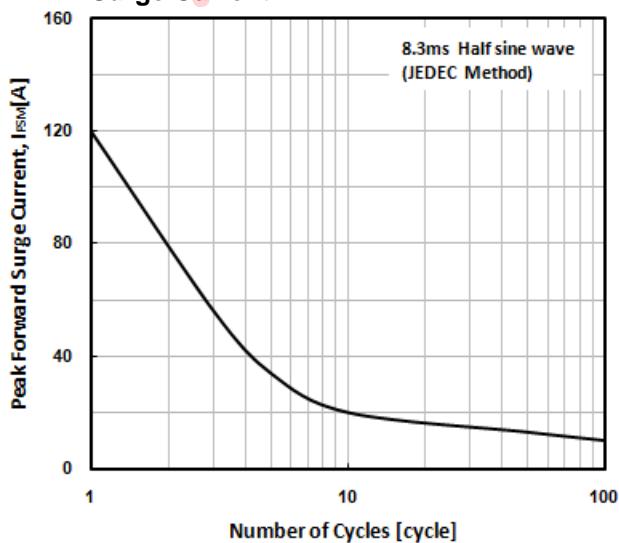
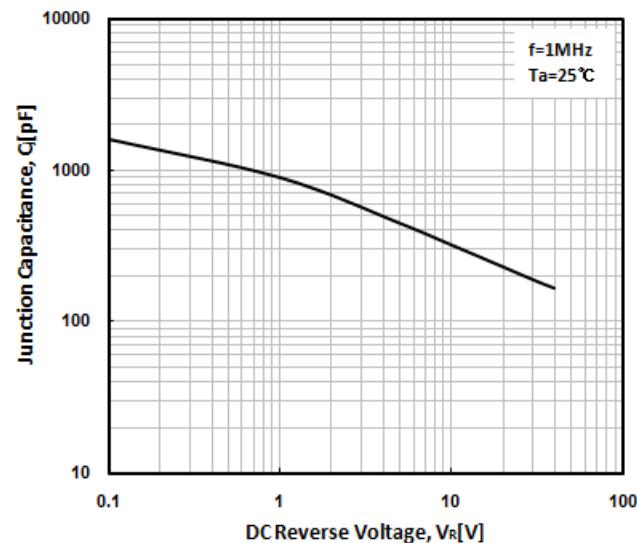
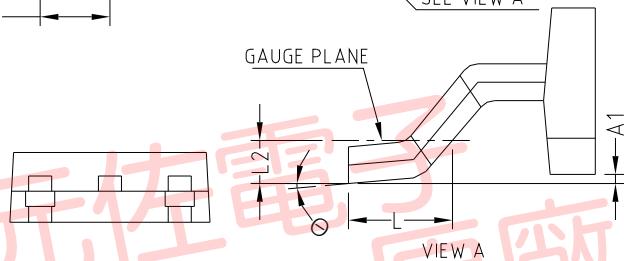
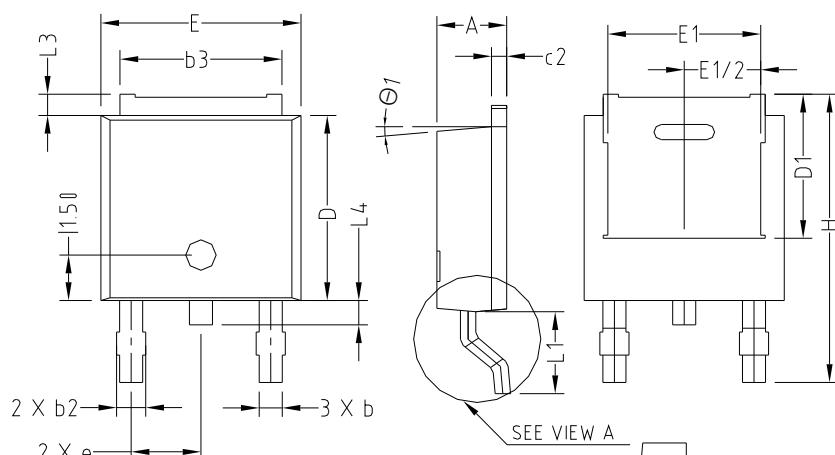


Fig. 6) Typical Junction Capacitance



**Package Outline Dimension**

SYMBOL	MILLIMETERS			NOTE
	MINIMUM	NOMINAL	MAXIMUM	
A	2.20	2.30	2.40	
A1	0.00		0.127	
b	0.66	0.76	0.86	
b2	-	-	0.96	
b3	5.04	5.34	5.64	
c2	0.40	0.50	0.60	
D	5.90	6.10	6.30	
D1		14.751		
E	6.40	6.60	6.80	
E1		15.041		
e		2.30 BSC		
H	9.20	9.50	9.80	
L	1.27	1.47	1.67	
L1	2.50	2.70	2.90	
L2		0.508 BSC		
L3	0.50	0.70	0.90	
L4	0.60	0.80	1.00	
Θ	0°	-	10°	
Θ1		5°		

**\* Recommended Land Pattern (Unit: mm)**